


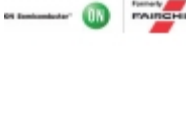


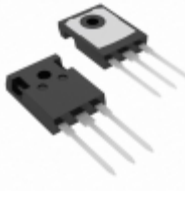
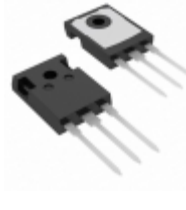
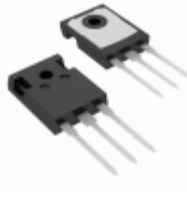
	<h2 style="color: red;">FGH40N6S2D</h2>
	<p>Hersteller-Teilenummer: FGH40N6S2D</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: IGBT 600V 75A 290W TO247</p> <p>Datenblätter:  FGH40N6S2D.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 12921 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FGH40N6S2D
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	IGBT 600V 75A 290W TO247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs-
Teilstatus	12921 pcs Stock
detaillierte Beschreibung	IGBT 600V 75A 290W Through Hole TO-247
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	290W
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Rückwärts-Erholzeit (Trr)	48ns
Strom - Kollektor (Ic) (max)	75A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	2.7V @ 15V, 20A
Strom - Collector Pulsed (Icm)	180A
Schaltenergie	115µJ (on), 195µJ (off)
Gate-Ladung	35nC
Td (ein / aus) bei 25 ° C	8ns/35ns
Testbedingung	390V, 20A, 3 Ohm, 15V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FGH40N6S2D_NL



FGH40N6S2D ist neu im Original, Suche FGH40N6S2D Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FGH40N6S2D AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FGH40N6S2D: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FGH40T100SMD-F155 AMI Semiconductor / ON Semiconductor IGBT 1000V 80A 333W TO247-3</p>	 <p>FGH40T100SMD AMI Semiconductor / ON Semiconductor IGBT 1000V 80A 333W TO247-3</p>	 <p>FGH40T100 Fairchild/ON Semiconductor FGH40T100 FAIRCHILD</p>	 <p>FGH40N65UFDTU-F085 AMI Semiconductor / ON Semiconductor IGBT 650V 40A 290W TO247</p>
 <p>FGH40T100SMD Fairchild/ON Semiconductor IGBT 1000V 80A 333W TO247-3</p>	 <p>FGH40N6S2 AMI Semiconductor / ON Semiconductor IGBT 600V 75A 290W TO247</p>	 <p>FGH40N6S2D Fairchild/ON Semiconductor IGBT 600V 75A 290W TO247</p>	 <p>FGH40N65UFDTU_F085 Fairchild/ON Semiconductor IGBT 650V 40A 290W TO247</p>

heiße Teile

Mehr

 FGH30N6S2D	 FGH30S130P	 FGH30S130P	 FGH30T65UPDT	 FGH40N60SF
 FGH40N60SFD	 FGH40N60SFDTU	 FGH40N60SFDTU	 FGH40N60SFTU	 FGH40N60SFTU
 FGH40N60SMD	 FGH40N60SMD	 FGH40N60SMD	 FGH40N60SMD	 FGH40N60UF
 FGH40N60UFD	 FGH40N60UFDTU	 FGH40N60UFDTU	 FGH40N60UFTU	 FGH40N60UFTU
 FGH40N65UFD	 FGH40N65UFDTU	 FGH40N65UFDTU	 FGH40N6S2	 FGH40N6S2
 FGH40N6S2D	 FGH40T100SMD	 FGH40T100SMD	 FGH40T120SMD	 FGH40T120SMD
 FGH40T65SHDF	 FGH40T65SPD	 FGH50N6S2	 FGH50N6S2	 FGH50N6S2D
 FGH50N6S2D	 FGH50T65SQD	 FGH50T65UPD	 FGH50T65UPD	 FGH60N60SF
 FGH60N60SFD	 FGH60N60SMD	 FGH60N60SMD	 FGH60N60UFD	 FGH60N6S2
 FGH60N6S2	 FGH60T65SHD	 FGH75N60SF	 FGH75N60SFTU	 FGH75N60SFTU

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited